

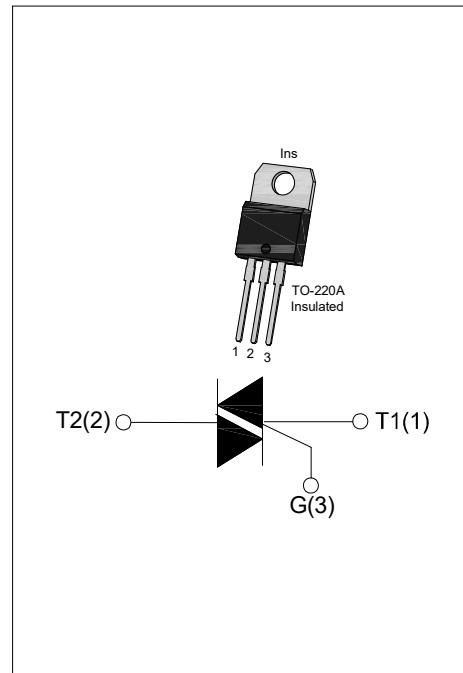


## JST12A-800CW 12A TRIACs

Rev.2

## DESCRIPTION:

With high ability to withstand the shock loading of large current, JST12A-800CW triacs provide high dv/dt rate with strong resistance to electromagnetic interface. With high commutation performances, especially recommended for use on inductive load. From all three terminals to external heatsink, JST12A-800CW provides a rated insulation voltage of 2500 V<sub>RMS</sub>, complying with UL standards. (File ref: E252906) Package TO-220A is RoHS compliant. (2011/65/EU)



## MAIN FEATURES

Symbol	Value	Unit
I <sub>T(RMS)</sub>	12	A
V <sub>DRM</sub> / V <sub>RRM</sub>	800	V

## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T <sub>stg</sub>	-40-150	°C
Operating junction temperature range	T <sub>j</sub>	-40-125	°C
Repetitive peak off-state voltage (T <sub>j</sub> =25°C)	V <sub>DRM</sub>	800	V
Repetitive peak reverse voltage (T <sub>j</sub> =25°C)	V <sub>RRM</sub>	800	V
RMS on-state current TO-220A(Ins) (T <sub>c</sub> =90°C)	I <sub>T(RMS)</sub>	12	A
Non repetitive surge peak on-state current (full cycle, F=50Hz)	I <sub>TSM</sub>	120	A
I <sup>2</sup> t value for fusing (tp=10ms)	I <sup>2</sup> t	78	A <sup>2</sup> s
Critical rate of rise of on-state current (I <sub>G</sub> =2×I <sub>GT</sub> )	dI/dt	50	A/μs
Peak gate current	I <sub>GM</sub>	4	A
Average gate power dissipation	P <sub>G(AV)</sub>	1	W
Peak gate power	P <sub>GM</sub>	5	W
Peak pulse voltage (T <sub>j</sub> =25°C; non-repetitive,off-state;FIG.7)	V <sub>pp</sub>	4	kV

ELECTRICAL CHARACTERISTICS ( $T_j=25^\circ\text{C}$  unless otherwise specified)

Symbol	Test Condition	Quadrant		Value	Unit
$I_{GT}$	$V_D = 12V$ $R_L = 33\Omega$	I - II - III	MAX	35	mA
$V_{GT}$		I - II - III	MAX	1.3	V
$V_{GD}$	$V_D = V_{DRM}$ $T_j = 125^\circ\text{C}$ $R_L = 3.3K\Omega$	I - II - III	MIN	0.2	V
$I_L$	$I_G = 1.2I_{GT}$	I - III	MAX	50	mA
		II		60	
$I_H$	$I_T = 100\text{mA}$		MAX	40	mA
$dv/dt$	$V_D = 2/3V_{DRM}$ Gate Open $T_j = 125^\circ\text{C}$		MIN	1000	V/ $\mu\text{s}$
$(dI/dt)_c$	Without snubber $T_j = 125^\circ\text{C}$		MIN	6.5	A/ms
$t_{on}$	$I_G = 40\text{mA}$ $I_A = 100\text{mA}$ $I_R = 10\text{mA}$ $T_j = 25^\circ\text{C}$		TYP	3	$\mu\text{s}$
$t_{off}$			TYP	50	$\mu\text{s}$

## STATIC CHARACTERISTICS

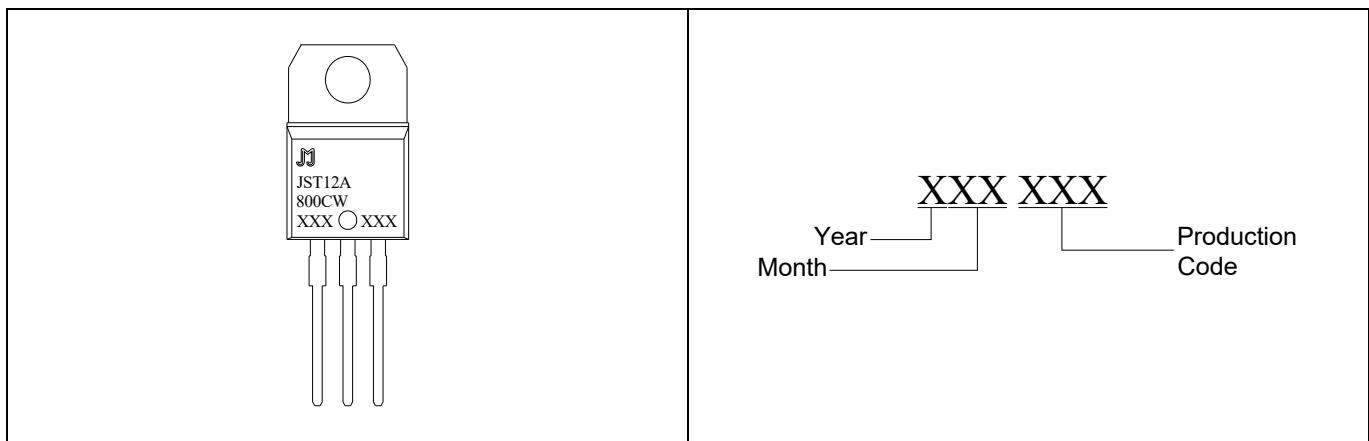
Symbol	Parameter		Value(MAX)	Unit
$V_{TM}$	$I_{TM} = 17\text{A}$	$t_p = 380\mu\text{s}$	$T_j = 25^\circ\text{C}$	1.5
$V_{TO}$	Threshold voltage		$T_j = 125^\circ\text{C}$	0.9
$R_d$	Dynamic resistance		$T_j = 125^\circ\text{C}$	$m\Omega$
$I_{DRM}$	$V_D = V_{DRM}$ $V_R = V_{RRM}$	$T_j = 25^\circ\text{C}$	5	$\mu\text{A}$
$I_{RRM}$		$T_j = 125^\circ\text{C}$	1	mA

## THERMAL RESISTANCES

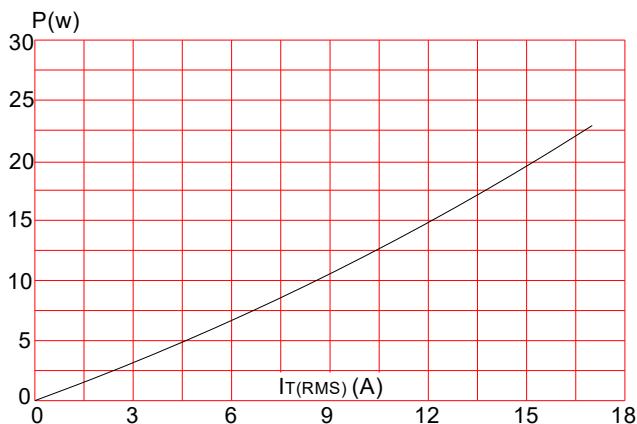
Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-220A(Ins)	2.3	$^\circ\text{C}/\text{W}$

**ORDERING INFORMATION**

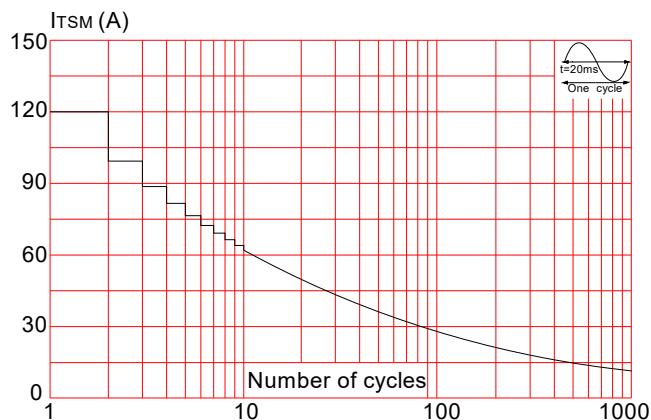
<u>J</u>	<u>ST</u>	<u>12</u>	<u>A</u>	<u>-800</u>	<u>CW</u>	<u>-/</u>
JieJie Microelectronics Co.,Ltd						
	Triacs					
		IT(RMS):12A				
			A:TO-220A(Ins)			
				800:V <sub>DRM</sub> / V <sub>RRM</sub> ≥ 800V		
						CW:I <sub>G</sub> T1-3 ≤ 35mA
						Blank: Tube

**MARKING**

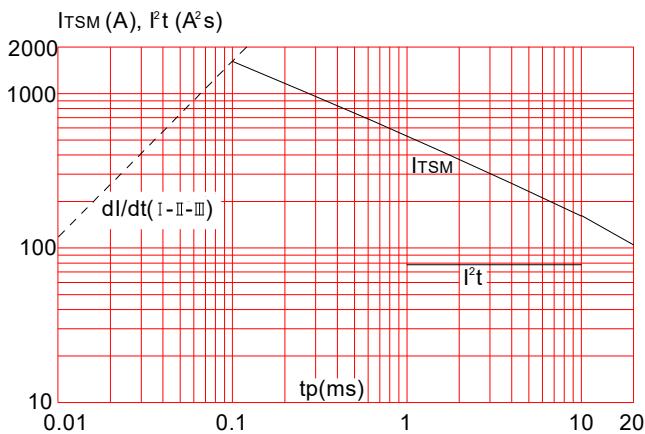
**FIG.1** Maximum power dissipation versus RMS on-state current



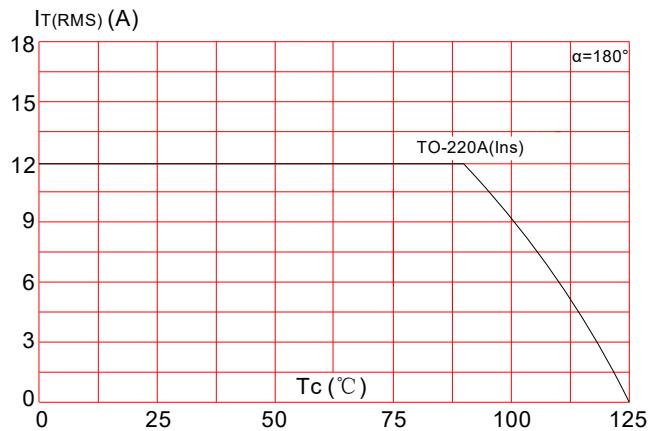
**FIG.3:** Surge peak on-state current versus number of cycles



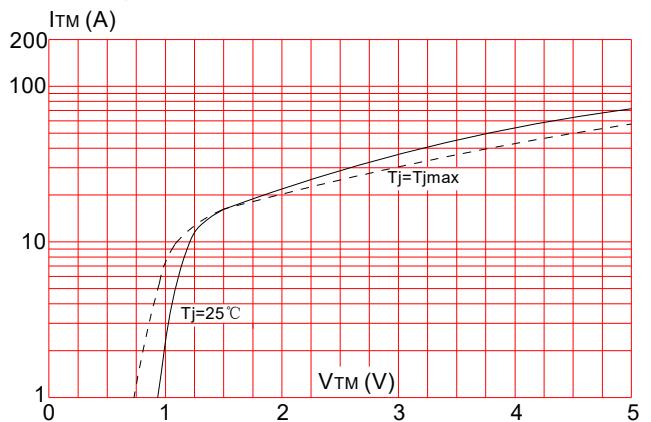
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $tp < 20\text{ms}$ , and corresponding value of  $\dot{I}^2t$  ( $dI/dt(I-I-III) < 50\text{A}/\mu\text{s}$ )



**FIG.2:** RMS on-state current versus case temperature



**FIG.4:** On-state characteristics (maximum values)



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

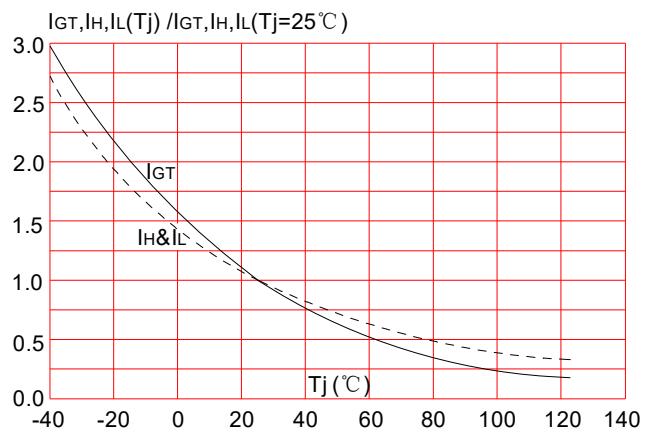
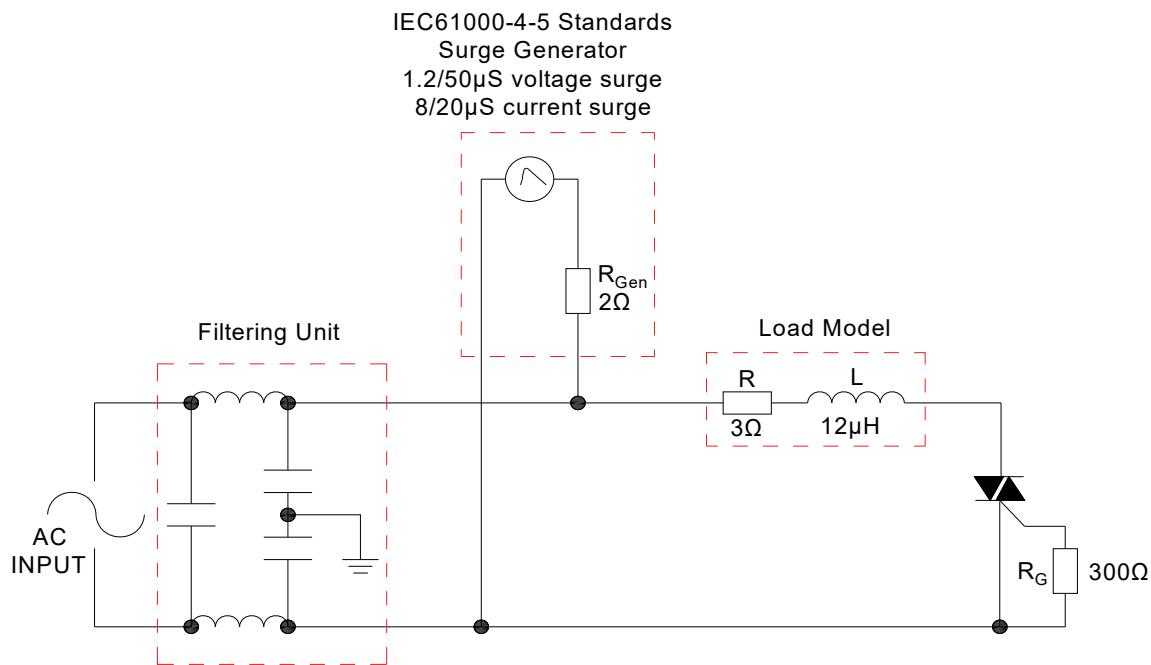


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



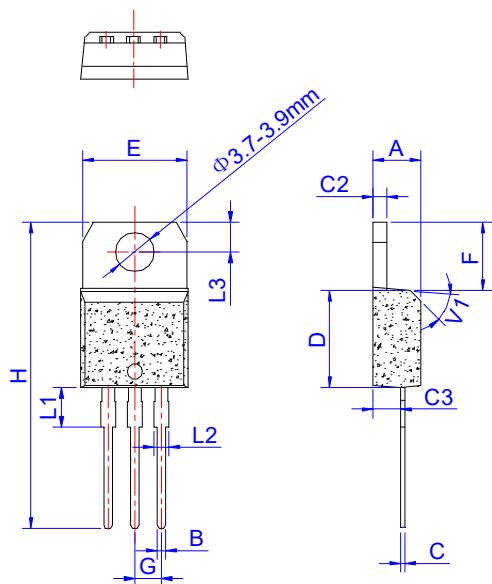
## ORDERING INFORMATION

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
JST12A-800CW	800	35	TO-220A(Ins)	50	Tube

## Document Revision History

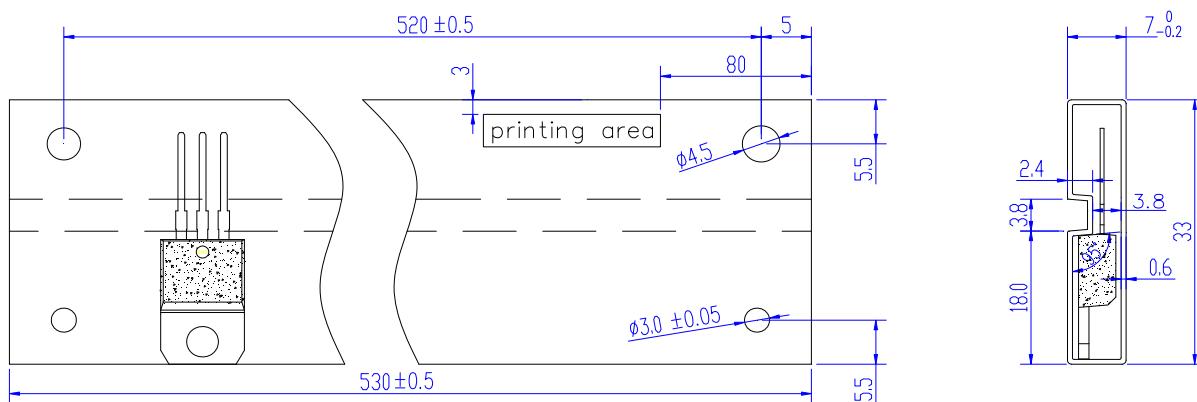
Date	Revision	Changes
Mar 27, 2022	1	Last update
Apr 25, 2022	2	Renew Vpp & $R_{th(j-c)}$ & FIG.2, Add $t_{on}$ & $t_{off}$

## PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.25		6.85	0.246		0.270
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
L1	3.45		4.05	0.136		0.159
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

## DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220A	TUBE	50	1,000	5,000



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